

ROM1490PS

The ROM1490PS uses Rakon's market-leading proprietary Mercury+™ technology, delivering the world's first ASIC-based and smallest OCXO in a hermetic package. This product family delivers ±10 ppb frequency stability over -40 to 85°C with short term ageing less than 1 ppb/day and frequency slope as low as 0.1 ppb/°C. Using Rakon's innovative high-Q quartz crystals, ROM1490PS offers superior close-in phase noise performance, enabling Remote Radio Head PLLs to use a single reference clock to meet both network synchronisation requirements and air interface requirements.

Mercury+™ ASIC-OCXOs enable lower Total Cost of Ownership of customer equipment through improved reliability. With a small form factor and few discrete components, a ROM1490PS consumes only 0.4W at room temperature and has faster warm up times than traditional OCXOs.

Features

- Superior close-in phase noise with high-Q SC-cut crystal
- < 1% VCO linearity</p>
- Patented tilt compensation for lifetime performance
- Fast warm up time
- Ultra-reliable OTP memory programming
- Lower customer Total Cost of Ownership through VLSI ASIC-integration

Applications

- Base Stations
- 5G RRH
- Small Cells
- Microwave transmission systems

14.2 x 9.2 x 6.5 mm



Standard Specifications

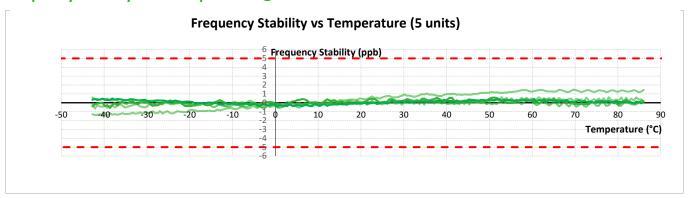
Parameter	Min.	Тур.	Max.	Unit	Test Condition / Description					
Nominal frequency		10 – 50		MHz	Standard frequencies: 10, 19.2, 20, 25, 30.72, 38.4, 50 MHz					
Frequency calibration			±0.2	ppm	Initial accuracy at 25°C ±2°C					
Reflow shift			±0.2	ppm	Pre to post reflow ΔF (measured ≥ 60 minutes after reflow)					
Operating temperature range	-40		+85	°C						
Frequency stability temperature			±10 ±5	ppb	In still air. Reference to (FMAX + FMIN)/2 ±10 ppb (Vc), ±5 ppb (Fixed frequency)					
Frequency slope $\Delta F/\Delta T$ in still air		±0.1	±0.5	ppb/°C	Temperature ramp ≤ 1°C/minute					
All causes stability			±4.6	ppm	Including calibration, temperature, supply voltage & load changes and 20 years life, reference to Fn					
Supply voltage stability		±5		ppb	±2% variation, reference to frequency at 3.3V					
Load sensitivity		±5		ppb	±10% variation, reference to frequency at 15p					
Warm-up time		15	60	sec	Time needed for frequency to be within ±20 ppb reference to frequency after 1 hour, at 25°C. Parameter is frequency, assembly and operating history dependent					
Long term stability (Ageing)		1	0.3 1.5	ppb ppm	Per day, after 60 days of continuous operation First year 10 years					
Supply voltage (Vcc)		2.7 – 5		V	±5%					
Input power		1200 400	1500 440	mW	Warm up Steady state in still air at 25°C					
Control voltage (Vc) ¹	0.25	1.25	2.25	V						
Frequency tuning	±1.9		±3.3	ppm	Reference to frequency at Vc=1.25V					
Linearity			1	%	Deviation from straight line curve fit					
Oscillator output	Regulate	Regulated CMOS output (1.0, 1.8, 2.5V) or standard CMOS (options)								

¹ The GND of the control voltage (Vc) needs to be connected directly to pin 2 (GND) as ground lead impedance may cause performance degradation.

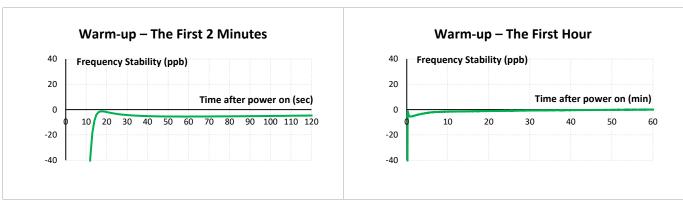


SSB Phase Noise	Frequency	1 Hz	10 Hz	100 Hz	1 kHz	10 kHz	100 kHz	1 MHz	Unit
(Typical value at 25°C)	19.2 MHz	-80	-110	-138	-154	-159	-160	-161	dBc/Hz
	30.72 MHz	-73	-105	-133	-153	-158	-160	-161	
	38.4 MHz	-70	-102	-132	-150	-155	-157	-159	

Frequency Stability over Temperature @ 19.2 MHz



Warm-up Time @ 19.2 MHz



Model Outline and Recommended Pad Layout

